



High-Speed CMOS 8 Input Multiplexers

QS54/74FCT151T
QS54/74FCT251T
QS54/74FCT2151T

FEATURES/BENEFITS

- Pin and function compatible to the 74F151/251 74FCT151/251 and 74FCT151T/251T
- Industrial temperature -40°C to 85°C
- CMOS power levels: $<7.5\text{mW}$ static
- Available in DIP, SOIC, QSOP, HQSOP
- Undershoot clamp diodes on all inputs
- TTL-compatible input and output levels
- Ground bounce controlled outputs
- Reduced output swing of 0-3.5V
- Military product compliant to MIL-STD-883, Class B

FCT-T 151T, 251T

- JEDEC-FCT spec compatible
- A and C speed grades with 4.5ns t_{PD} for C
- $I_{\text{OL}} = 48\text{mA}$ Ind., 32mA Mil.

FCT-T 2151T

- Built-in 25Ω series resistor outputs reduce reflection and other system noise
- Std., A, and C speed grades with 4.5ns t_{PD} for C
- $I_{\text{OL}} = 12\text{mA}$ Ind.

DESCRIPTION

The QSFCT151T and QSFCT251T are high-speed CMOS TTL-compatible 8-input multiplexers. The 151 has TTL outputs; the 251 has 3-state outputs. The QSFCT2151T is a 25Ω resistor output version useful for driving transmission lines and reducing system noise. All inputs have clamp diodes for undershoot noise suppression. All outputs have ground bounce suppression (see QSI Application Note AN-001). Outputs will not load an active bus when V_{CC} is removed from the device.

Figure 1. Functional Block Diagram

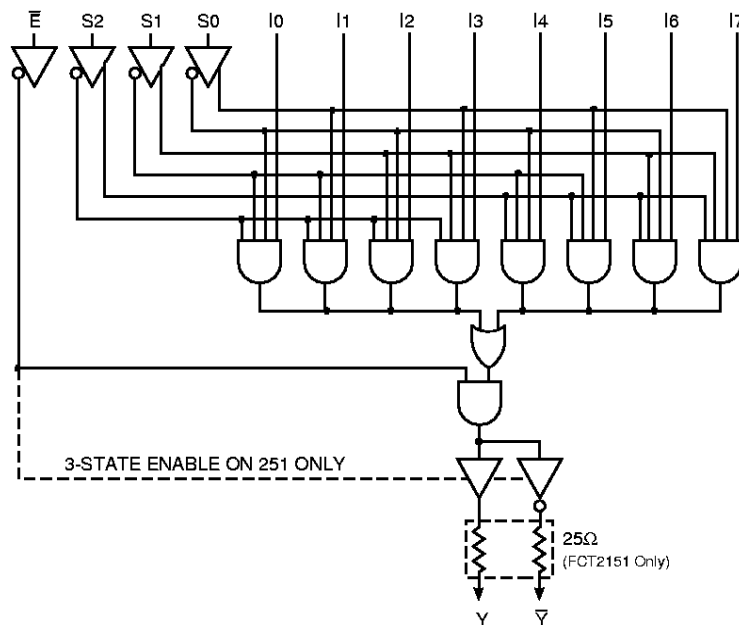
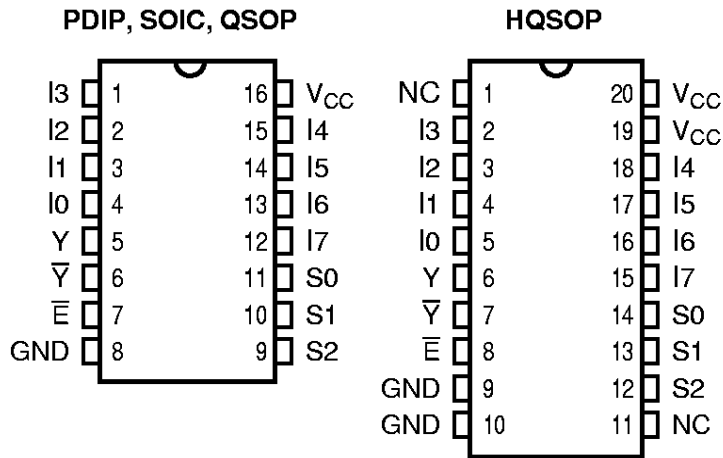


Figure 2. Pin Configurations (All Pins Top View)



Note:
Available in both 150 mil wide SOIC (package code S1)
and 300 mil SOIC (package code S0).

Table 1. Pin Description

Name	I/O	Description
I7-I0	I	Data In
S2-S0	I	Select
\bar{E}	I	Enable
Y, \bar{Y}	O	Data Out

Table 2. Function Table

\bar{E}	Select			151, 2151		251		Function
	S2	S1	S0	Y	\bar{Y}	Y	\bar{Y}	
H	X	X	X	L	H	HI-Z	HI-Z	Disable
L	L	L	L	I0	$\bar{I0}$	I0	$\bar{I0}$	S2-0 = 0
L	L	L	H	I1	$\bar{I1}$	I1	$\bar{I1}$	S2-0 = 1
L	L	H	L	I2	$\bar{I2}$	I2	$\bar{I2}$	S2-0 = 2
L	L	H	H	I3	$\bar{I3}$	I3	$\bar{I3}$	S2-0 = 3
L	H	L	L	I4	$\bar{I4}$	I4	$\bar{I4}$	S2-0 = 4
L	H	L	H	I5	$\bar{I5}$	I5	$\bar{I5}$	S2-0 = 5
L	H	H	L	I6	$\bar{I6}$	I6	$\bar{I6}$	S2-0 = 6
L	H	H	H	I7	$\bar{I7}$	I7	$\bar{I7}$	S2-0 = 7

Table 3. Absolute Maximum Ratings

Supply Voltage to Ground	-0.5V to 7.0V
DC Output Voltage V_{OUT}	-0.5V to 7.0V
DC Input Voltage V_{IN}	-0.5V to 7.0V
AC Input Voltage (for a pulse width $\leq 20\text{ns}$)	-3.0V
DC Input Diode Current with $V_{IN} < 0$	-20mA
DC Output Diode Current with $V_{OUT} < 0$	-50mA
DC Output Current Max. Sink Current/Pin	120mA
Maximum Power Dissipation	0.5 watts
T_{STG} Storage Temperature	-65° to 150°C

Note: Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to this device resulting in functional or reliability type failures.

Table 4. Capacitance⁽¹⁾

$T_A = 25^\circ\text{C}$, $f = 1\text{MHz}$, $V_{IN} = 0\text{V}$, $V_{OUT} = 0\text{V}$

Pins ⁽²⁾	SOIC	QSOP	PDIP	Unit
1-3, 10, 11, 13-15	4	4	5	pF
4-7, 9, 12	8	8	9	pF

Notes:

1. Capacitance is characterized but not tested.
2. Pin reference for 16-pin package.

Table 5. Power Supply Characteristics

Symbol	Parameter	Test Conditions ⁽¹⁾	Min	Max	Unit
I_{CC}	Quiescent Power Supply Current	$V_{CC} = \text{Max.}$, freq = 0 $0\text{V} \leq V_{IN} \leq 0.2\text{V}$ or $V_{CC}-0.2\text{V} \leq V_{IN} \leq V_{CC}$	—	1.5	mA
ΔI_{CC}	Supply Current per Input @ TTL HIGH	$V_{CC} = \text{Max.}$, $V_{IN} = 3.4\text{V}$, freq = 0 ⁽²⁾	—	2.0	mA
Q_{CCD}	Supply Current per Input per MHz	$V_{CC} = \text{Max.}$, Outputs Open and Enabled One Bit Toggling @ 50% Duty Cycle Other Inputs at GND or V_{CC} ^(3,4)	—	0.25	mA/ MHz

Notes:

1. For conditions shown as Min. or Max., use the appropriate values specified under DC specifications.
2. Per TTL driven input ($V_{IN} = 3.4\text{V}$).
3. For flip-flops, Q_{CCD} is measured by switching one of the data input pins so that the output changes every clock cycle. This is a measurement of device power consumption only and does not include power to drive load capacitance or tester capacitance. This parameter is guaranteed by design but not tested.
4. I_C can be computed using the above parameters as explained in the Technical Overview section.

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Table 6. DC Electrical Characteristics Over Operating Range

Industrial $T_A = -40^{\circ}\text{C}$ to 85°C , $V_{CC} = 5.0\text{V} \pm 5\%$

Military $T_A = -55^{\circ}\text{C}$ to 125°C , $V_{CC} = 5.0\text{V} \pm 10\%$

Symbol	Parameter	Test Conditions	Min	Typ ⁽¹⁾	Max	Unit
V_{IH}	Input HIGH Voltage	Logic HIGH for All Inputs	2.0	—	—	V
V_{IL}	Input LOW Voltage	Logic LOW for All Inputs	—	—	0.8	V
ΔV_T	Input Hysteresis	$V_{TLH} - V_{THL}$ for All Inputs	—	0.2	—	V
$ I_{IH} $ $ I_{IL} $	Input Current Input HIGH or LOW	$V_{CC} = \text{Max.}, 0 \leq V_{IN} < V_{CC}$	—	—	5	μA
$ I_{OZ} $	Off-State Output Current (Hi-Z)(FCT251)	$V_{CC} = \text{Max.}, 0 \leq V_{IN} \leq V_{CC}$	—	—	5	μA
I_{OS}	Short Circuit Current (FCTXXX)	$V_{CC} = \text{Max.}, V_{OUT} = \text{GND}^{(2,3)}$	-60	—	—	mA
I_{OR}	Current Drive (FCT2151)	$V_{CC} = \text{Max.}, V_{OUT} = 2.0\text{V}^{(3)}$	50	—	—	mA
V_{IC}	Input Clamp Voltage	$V_{CC} = \text{Min.}, I_{IN} = -18\text{mA}, T_A = 25^{\circ}\text{C}^{(3)}$	—	-0.7	-1.2	V
V_{OH}	Output HIGH Voltage	$V_{CC} = \text{Min.}, I_{OH} = -12\text{mA}$ (MIL) $I_{OH} = -15\text{mA}$ (IND)	2.4 2.4	— —	— —	V
V_{OL}	Output LOW Voltage (FCTXXX)	$V_{CC} = \text{Min.}, I_{OL} = 32\text{mA}$ (MIL) $I_{OL} = 48\text{mA}$ (IND)	— —	— —	0.50 0.50	V
V_{OL}	Output LOW Voltage (FCT2151- 25 Ω)	$V_{CC} = \text{Min.}, I_{OL} = 12\text{mA}$ (MIL) $I_{OL} = 12\text{mA}$ (IND)	— —	— —	0.50 0.50	V
R_{OUT}	Output Resistance (FCT2151- 25 Ω)	$V_{CC} = \text{Min.}, I_{OL} = 12\text{mA}$ (MIL) $I_{OL} = 12\text{mA}$ (IND)	— 20	25 28	— 40	Ω

Notes:

1. Typical values indicate $V_{CC} = 5.0\text{V}$ and $T_A = 25^{\circ}\text{C}$.
2. Not more than one output should be shorted and the duration is ≤ 1 second.
3. These parameters are guaranteed by design but not tested.

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Table 7. Switching Characteristics Over Operating Range

Industrial $T_A = -40^\circ\text{C}$ to 85°C , $V_{CC} = 5.0\text{V} \pm 5\%$

Military $T_A = -55^\circ\text{C}$ to 125°C , $V_{CC} = 5.0\text{V} \pm 10\%$

$C_{LOAD} = 50\text{pF}$, $R_{LOAD} = 500\Omega$ unless otherwise noted.

Symbol	Description ⁽¹⁾		2151		151A 251A 2151A		151C 2151C		Unit
			Min	Max	Min	Max	Min	Max	
t_{Y}	Propagation Delay In to Y or \bar{Y} , 151/251	Ind	1.5	7	1.5	5.2	1.5	4.5	ns
		Mil	1.5	8	1.5	5.8	1.5	5.2	
t_{Y}	Propagation Delay In to Y or \bar{Y} , 2151	Ind	1.5	7	1.5	5.2	1.5	4.5	ns
		Mil	1.5	8	1.5	5.8	1.5	5.2	
t_{SY}	Propagation Delay Sn to Y or \bar{Y} , 151/251	Ind	1.5	9	1.5	6.6	1.5	5.9	ns
		Mil	1.5	9.5	1.5	7.4	1.5	6.5	
t_{SY}	Propagation Delay In to Y or \bar{Y} , 2151	Ind	1.5	9	1.5	6.6	1.5	5.9	ns
		Mil	1.5	9.5	1.5	7.4	1.5	6.5	
t_{OEH} t_{OEL}	Output Enable Time \bar{E} to Yi, 151	Ind	1.5	7	1.5	5.2	1.5	4.5	ns
		Mil	1.5	8	1.5	5.8	1.5	5.2	
t_{OEH} t_{OEL}	Output Enable Time \bar{E} to Yi, 2151	Ind	1.5	7	1.5	5.2	1.5	4.5	ns
		Mil	1.5	8	1.5	5.8	1.5	5.2	
t_{PZH} t_{PZL}	Output Enable Time \bar{E} to Yi, 251	Ind	1.5	9	1.5	6.0	1.5	5.0	ns
		Mil	1.5	10	1.5	6.4	1.5	5.5	
t_{PHZ} t_{PLZ}	Output Disable Time ⁽²⁾ \bar{E} to Yi, 251	Ind	1.5	7	1.5	6	1.5	5.0	ns
		Mil	1.5	7	1.5	6.3	1.5	5.5	

Notes:

1. Minimums guaranteed but not tested.
2. This parameter is guaranteed by design but not tested.
3. See Test Circuit and Waveforms.